

1A High-Speed MOSFET Drivers

Features

- Latch-Up Protected: Withstands 500 mA Reverse Current
- · Input Withstands Negative Inputs Up to 5V
- Electrostatic Discharge (ESD) Protected: 2.0 kV (HBM) and 400V (MM)
- · High Peak Output Current: 1A
- · Wide Input Supply Voltage Operating Range:
 - 4.5V to 16V
- · High Capacitive Load Drive Capability:
 - 1000 pF in 25 ns
- · Short Delay Time: 30 ns typical
- · Matched Delay Times
- · Low Supply Current
 - With Logic '1' Input: 500 μA
 - With Logic '0' Input: 100 µA
- Low Output Impedance: 8Ω
- · Available in Space-Saving 8-pin MSOP Package
- Pinout same as TC1410/TC1412/TC1413

Applications

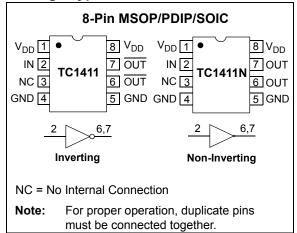
- · Switch Mode Power Supplies
- · Pulse Transformer Drive
- · Line Drivers
- · Relay Driver

General Description

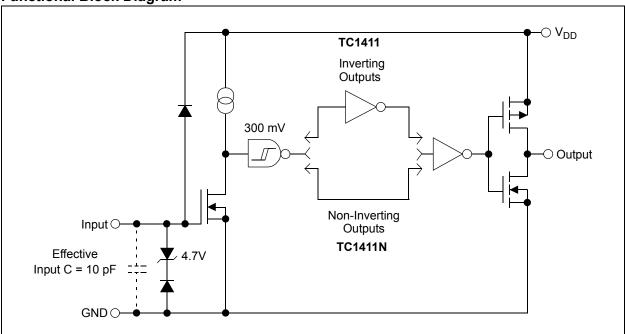
The TC1411/TC1411N are 1A CMOS buffers/drivers. They do not latch up under any conditions within their power and voltage ratings. They are not subject to damage when up to 5V of noise spiking of either polarity occurs on the ground pin. They can accept, without damage or logic upset, up to 500 mA of current of either polarity being forced back into their output. All terminals are fully protected against Electrostatic Discharge (ESD) up to 2.0 kV (HBM) and 400V (MM).

As MOSFET drivers, the TC1411/TC1411N can easily charge a 1000 pF gate capacitance in 25 ns with matched rise and fall times. To ensure that the MOSFET's intended state is not affected even by large transients, low enough impedance in both the 'ON' and 'OFF' states are provided. The leading and trailing edge propagation delay times are also matched to allow driving short-duration inputs with greater accuracy.

Package Types



Functional Block Diagram



1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings †

Supply Voltage	+20V
Input Voltage	$V_{DD} + 0.3V$ to GND $-5.0V$
Power Dissipation (T _A ≤ 70	°C)
MSOP	340 mW
PDIP	730 mW
SOIC	470 mW
Storage Temperature Rang	e65°C to +150°C
Maximum Junction Temper	rature +150°C

 V_{IL}

† Notice: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions above those indicated in the operation sections of the specifications is not implied. Exposure to Absolute Maximum Rating conditions for extended periods may affect device reliability.

DC CHARACTERISTICS

Logic '0', Low Input Voltage

Typical values are measured at $T_A = +25^{\circ}C$, $V_{DD} = 16V$.						
Parameters Sym Min Typ Max Units Conditions						
Input						
Logic '1', High Input Voltage	V _{IH}	2.0	_	_	V	

8.0

Input Current	I _{IN}	-1.0	_	1.0	μA	$0V \le V_{IN} \le V_{DD}, T_A = +25^{\circ}C$
		-10	_	10		$-40^{\circ}\text{C} \le \text{T}_{\text{A}} \le +85^{\circ}\text{C}$
Output		•				
High Output Voltage	V _{OH}	V _{DD} – 0.025	_	_	V	DC Test
Low Output Voltage	V _{OL}	_	_	0.025	V	DC Test
Output Resistance	R _O	_	8	11	Ω	$V_{DD} = 16V, I_{O} = 10 \text{ mA},$ $T_{A} = +25^{\circ}\text{C}$
		_	10	14		$0^{\circ}\text{C} \leq \text{T}_{\text{A}} \leq +70^{\circ}\text{C}$
			10	14		$-40^{\circ}\text{C} \le \text{T}_{\text{A}} \le +85^{\circ}\text{C}$
Peak Output Current	I _{PK}	_	1.0	_	Α	V _{DD} = 16V
Latch-Up Protection Withstand Reverse Current	I _{REV}	_	0.5	_	Α	Duty cycle \leq 2%, t \leq 300 μ s, V_{DD} = 16V
Switching Time (Note 1)	•				•	
Rise Time	t _R	_	25	35	ns	T _A = +25°C
			27	40		0°C ≤ T _A ≤ +70°C
			29	40		-40°C ≤ T _A ≤ +85°C, Figure 4-1
Fall Time	t _F	_	25	35	ns	T _A = +25°C
			27	40		0°C ≤ T _A ≤ +70°C
		_	29	40		-40°C ≤ T _A ≤ +85°C, Figure 4-1
Delay Time	t _{D1}	_	30	40	ns	T _A = +25°C

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45

Note 1: Switching times ensured by design.

 t_{D2}

Delay Time

 $0^{\circ}C \le T_A \le +70^{\circ}C$

 $0^{\circ}C \le T_A \le +70^{\circ}C$

 $T_A = +25^{\circ}C$

 $-40^{\circ}\text{C} \le \text{T}_{\text{A}} \le +85^{\circ}\text{C}$, Figure 4-1

-40°C $\leq T_A \leq +85$ °C, Figure 4-1

DC CHARACTERISTICS (CONTINUED)

Electrical Specifications: Unless otherwise noted, over the operating temperature range with $4.5V \le V_{DD} \le 16V$. Typical values are measured at $T_{\Delta} = +25^{\circ}C$, $V_{DD} = 16V$.

Typical talace are measured at TA 125 C, TDD 101.						
Parameters	Sym	Min	Тур	Max	Units	Conditions
Power Supply						
Power Supply Current	I _S	_	0.5	1.0	mA	V _{IN} = 3V, V _{DD} = 16V
		_	0.1	0.15		V _{IN} = 0V

Note 1: Switching times ensured by design.

TEMPERATURE CHARACTERISTICS

Electrical Specifications: Unless otherwise noted, all parameters apply with $4.5 \text{V} \le \text{V}_{DD} \le 16 \text{V}$.							
Parameters	Sym	Min	Тур	Max	Units	Conditions	
Temperature Ranges							
Specified Temperature Range (C)	T_A	0	_	+70	°C		
Specified Temperature Range (E)	T _A	-40	_	+85	°C		
Specified Temperature Range (V)	T _A	-40	_	+125	°C		
Maximum Junction Temperature	T_J	_	_	+150	°C		
Storage Temperature Range	T _A	-65	_	+150	°C		
Package Thermal Resistances	Package Thermal Resistances						
Thermal Resistance, 8L-MSOP	θ_{JA}	_	211	_	°C/W		
Thermal Resistance, 8L-PDIP	θ_{JA}	_	89.3	_	°C/W		
Thermal Resistance, 8L-SOIC	θ_{JA}	_	149.5	_	°C/W		

2.0 TYPICAL PERFORMANCE CURVES

Note: The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.

Note: Unless otherwise indicated, over operating temperature range with $4.5V \le V_{DD} \le 16V$.

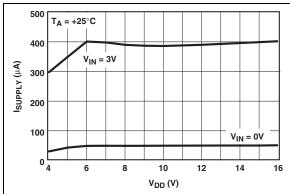


FIGURE 2-1: Quiescent Supply Current vs. Supply Voltage.

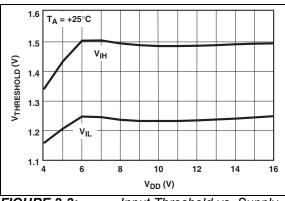


FIGURE 2-2: Input Threshold vs. Supply Voltage.

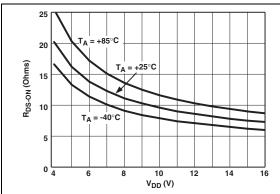


FIGURE 2-3: High-State Output Resistance vs. Supply Voltage.

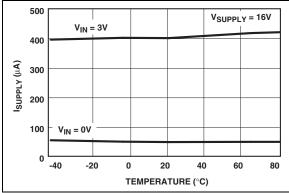


FIGURE 2-4: Quiescent Supply Current vs. Temperature.

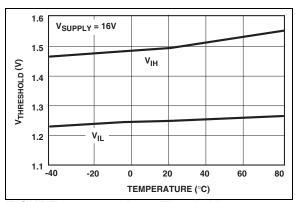


FIGURE 2-5: Input Threshold vs. Temperature.

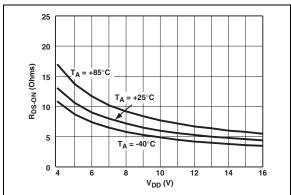


FIGURE 2-6: Low-State Output Resistance vs. Supply Voltage.

Note: Unless otherwise indicated, over operating temperature range with $4.5 \text{V} \leq \text{V}_{DD} \leq 16 \text{V}$.

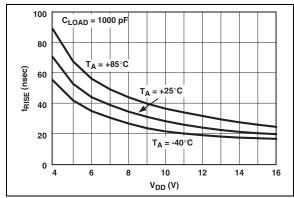


FIGURE 2-7: Voltage.

Rise Time vs. Supply

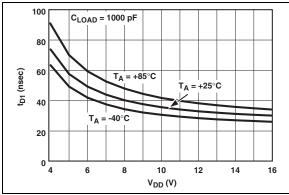


FIGURE 2-8: Supply Voltage.

Propagation Delay vs.

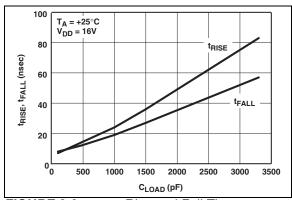


FIGURE 2-9: Capacitive Load.

Rise and Fall Times vs.

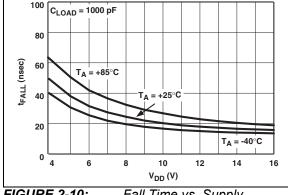


FIGURE 2-10: Voltage.

-10: Fall Time vs. Supply

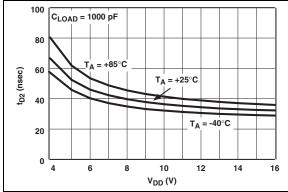


FIGURE 2-11: Supply Voltage.

Propagation Delay vs.

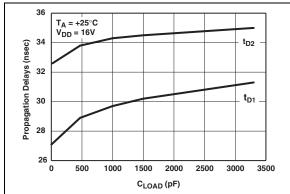


FIGURE 2-12: Capacitive Load.

Propagation Delays vs.

3.0 PIN DESCRIPTIONS

The descriptions of the pins are listed in Table 3-1.

TABLE 3-1: PIN FUNCTION TABLE

Pin No.	TC1411 MSOP, PDIP, SOIC	TC1411N MSOP, PDIP, SOIC	Description
1	V_{DD}	V_{DD}	Supply input, 4.5V to 16V
2	IN	IN	Control input
3	NC	NC	No connection
4	GND	GND	Ground
5	GND	GND	Ground
6	OUT	OUT	CMOS push-pull output, common to pin 7
7	OUT	OUT	CMOS push-pull output, common to pin 6
8	V_{DD}	V_{DD}	Supply input, 4.5V to 16V

3.1 Supply Input (V_{DD})

The V_{DD} input is the bias supply for the MOSFET driver and is rated for 4.5V to 16V with respect to the ground pin. The V_{DD} input should be bypassed to ground with a local ceramic capacitor. The value of the capacitor is chosen based on the capacitive load that is being driven. A value of 1.0 μ F is suggested.

3.2 Control Input (IN)

The MOSFET driver input is a high-impedance, TTL/CMOS-compatible input. The input has 300 mV of hysteresis between the high and low thresholds that prevents output glitching even when the rise and fall time of the input signal is very slow.

3.3 CMOS Push-pull Output (OUT, OUT)

The MOSFET driver output is a low impedance, CMOS push-pull style output, capable of driving a capacitive load with 1A peak currents.

3.4 Ground (GND)

The ground pins are the return path for the bias current and for the high peak currents which discharge the load capacitor. The ground pins should be tied into a ground plane or have very short traces to the bias supply source return.

3.5 No Connect (NC)

No internal connection.

4.0 APPLICATION INFORMATION

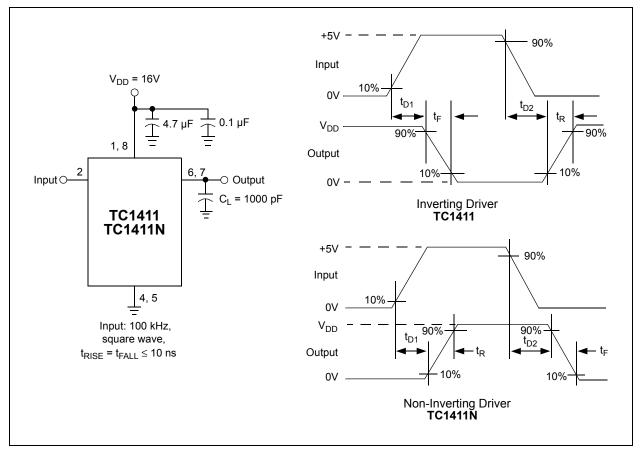
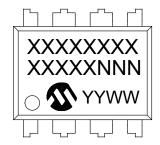


FIGURE 4-1: Switching Time Test Circuit.

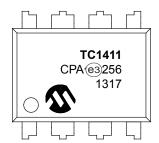
5.0 PACKAGING INFORMATION

5.1 Package Marking Information

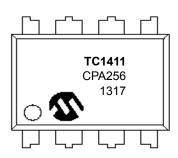
8-Lead PDIP (300 mil)







OR



Legend: XX...X Customer-specific information

Y Year code (last digit of calendar year)
YY Year code (last 2 digits of calendar year)
WW Week code (week of January 1 is week '01')

NNN Alphanumeric traceability code

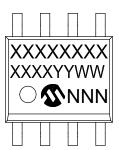
(e3) RoHS Compliant JEDEC designator for Matte Tin (Sn)

* This package is RoHS Compliant. The RoHS Compliant JEDEC designator ((e3))

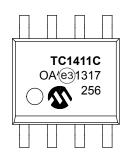
can be found on the outer packaging for this package.

Note: In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line, thus limiting the number of available characters for customer-specific information.

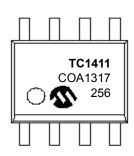
8-Lead SOIC (3.90 mm)



Example



OR



8-Lead MSOP (3x3 mm)

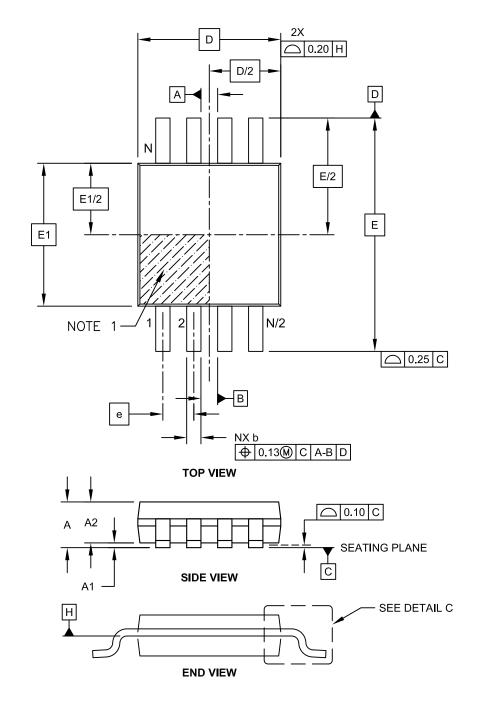


Example



8-Lead Plastic Micro Small Outline Package (UA) [MSOP]

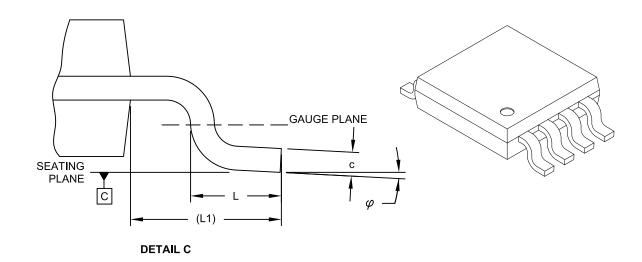
Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Microchip Technology Drawing C04-111C Sheet 1 of 2

8-Lead Plastic Micro Small Outline Package (UA) [MSOP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	MILLIMETERS			
Dimension Limits		MIN	NOM	MAX
Number of Pins	N		8	
Pitch	е		0.65 BSC	
Overall Height	Α	-	-	1.10
Molded Package Thickness	A2	0.75	0.85	0.95
Standoff	A1	0.00	-	0.15
Overall Width	E	4.90 BSC		
Molded Package Width	E1		3.00 BSC	
Overall Length	D		3.00 BSC	
Foot Length	L	0.40	0.60	0.80
Footprint	L1		0.95 REF	
Foot Angle	φ	0°	-	8°
Lead Thickness	С	0.08	-	0.23
Lead Width	b	0.22	-	0.40

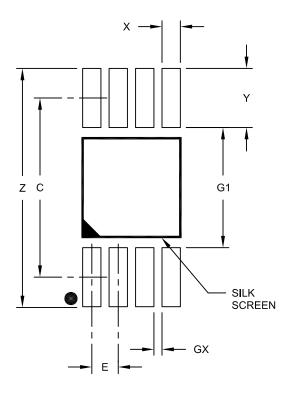
Notes:

- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.15mm per side.
- 3. Dimensioning and tolerancing per ASME Y14.5M.
 - BSC: Basic Dimension. Theoretically exact value shown without tolerances.
 - REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-111C Sheet 2 of 2

8-Lead Plastic Micro Small Outline Package (UA) [MSOP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

	I.	II LLIMETER	S	
Dimension	Limits	MIN	NOM	MAX
Contact Pitch	Е	0.65 BSC		
Contact Pad Spacing	C		4.40	
Overall Width	Z			5.85
Contact Pad Width (X8)	X1			0.45
Contact Pad Length (X8)	Y1			1.45
Distance Between Pads	G1	2.95		
Distance Between Pads	GX	0.20		

Notes:

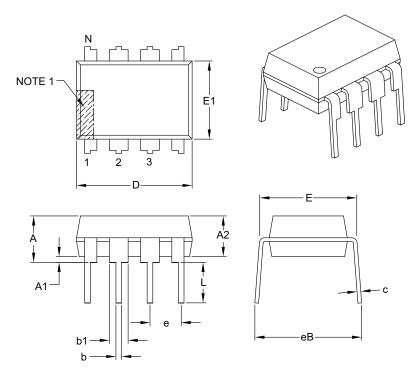
1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2111A

8-Lead Plastic Dual In-Line (PA) - 300 mil Body [PDIP]

bte: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units		INCHES		
	Dimension Limits	MIN	NOM	MAX	
Number of Pins	N		8		
Pitch	е		.100 BSC		
Top to Seating Plane	А	_	-	.210	
Molded Package Thickness	A2	.115	.130	.195	
Base to Seating Plane	A1	.015	_	-	
Shoulder to Shoulder Width	E	.290	.310	.325	
Molded Package Width	E1	.240	.250	.280	
Overall Length	D	.348	.365	.400	
Tip to Seating Plane	L	.115	.130	.150	
Lead Thickness	С	.008	.010	.015	
Upper Lead Width	b1	.040	.060	.070	
Lower Lead Width	b	.014	.018	.022	
Overall Row Spacing §	eB	_	_	.430	

Notes:

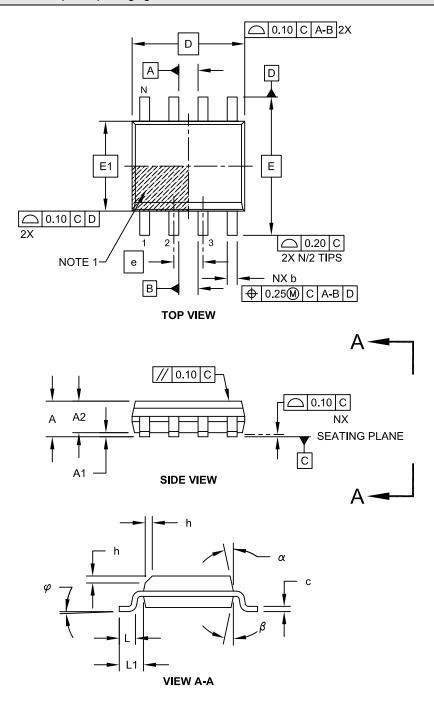
- 1. Pin 1 visual index feature may vary, but must be located with the hatched area.
- 2. § Significant Characteristic.
- 3. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" per side.
- 4. Dimensioning and tolerancing per ASME Y14.5M.

 ${\tt BSC: Basic \ Dimension. \ Theoretically \ exact \ value \ shown \ without \ tolerances.}$

Microchip Technology Drawing C04-018B

8-Lead Plastic Small Outline (OA) - Narrow, 3.90 mm Body [SOIC]

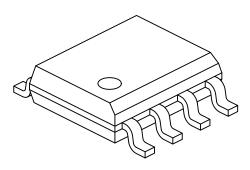
Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Microchip Technology Drawing No. C04-057C Sheet 1 of 2 $\,$

8-Lead Plastic Small Outline (OA) - Narrow, 3.90 mm Body [SOIC]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	MILLIMETERS			
Dimension	Limits	MIN	NOM	MAX
Number of Pins	N		8	
Pitch	е		1.27 BSC	
Overall Height	Α	-	1	1.75
Molded Package Thickness	A2	1.25	ı	=
Standoff §	A1	0.10	ı	0.25
Overall Width	Е	6.00 BSC		
Molded Package Width	E1	3.90 BSC		
Overall Length	D		4.90 BSC	
Chamfer (Optional)	h	0.25	ı	0.50
Foot Length	L	0.40	ı	1.27
Footprint	L1		1.04 REF	
Foot Angle	φ	0°	-	8°
Lead Thickness	С	0.17	ı	0.25
Lead Width	b	0.31	-	0.51
Mold Draft Angle Top	α	5°	-	15°
Mold Draft Angle Bottom	β	5°		15°

Notes:

- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. § Significant Characteristic
- 3. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.15mm per side.
- 4. Dimensioning and tolerancing per ASME Y14.5M

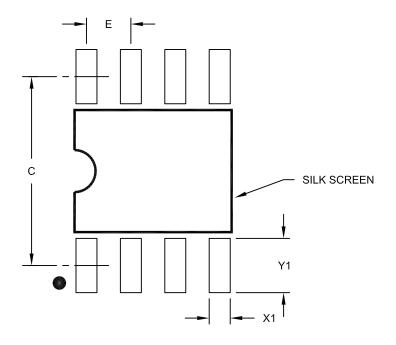
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing No. C04-057C Sheet 2 of 2

8-Lead Plastic Small Outline (OA) - Narrow, 3.90 mm Body [SOIC]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

	M	IILLIMETER	S	
Dimension Limits		MIN	NOM	MAX
Contact Pitch	Е		1.27 BSC	
Contact Pad Spacing	С		5.40	
Contact Pad Width (X8)	X1			0.60
Contact Pad Length (X8)	Y1			1.55

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2057A

NOTES:

APPENDIX A: REVISION HISTORY

Revision E (June 2013)

The following is the list of modifications:

- Updated the values for Electrostatic Discharge (ESD) in the Features and General Description columns.
- Updated the Pin Description table in Section 3.0, Pin Descriptions.
- Updated package marking information and drawings in Section 5.0, Packaging Information.
- · Minor grammatical and spelling corrections.

Revision D (September 2006)

- Added -40°C to +125°C temperature range to Temperature Characteristics table and Product Information System page.
- · Added disclaimer to package outline drawings.

Revision C (March 2003)

• Added 8-Lead MSOP Package.

Revision B (May 2002)

 Converted TELCOM data sheet for Embedded Control Handbook

Revision A (March 2001)

· Original Release of this Document.

NOTES:

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

PART NO. X /XX	Examples:
 Device Temperature Package Range	a) TC1411COA: 1A Single MOSFET driver, 8LD SOIC package, 0°C to +70°C.
Device: TC1411: 1 A Single MOSFET Driver, Inverting TC1411N: 1 A Single MOSFET Driver, Non-Inverting	b) TC1411CPA: 1A Single MOSFET driver, 8LD PDIP package, 0°C to +70°C.
Temperature Range: C = 0°C to +70°C E = -40°C to +85°C V = -40°C to +125°C	c) TC1411EUA713: Tape and Reel, 1A Single MOSFET driver, 8LD MSOP package, -40°C to +85°C.
Package: OA = Plastic SOIC, (150 mil Body), 8-lead OA713 = Plastic SOIC, (150 mil Body), 8-lead (Tape and Reel) UA = Plastic Micro Small Outline (MSOP), 8-lead * UA713 = Plastic Micro Small Outline (MSOP), 8-lead * (Tape and Reel)	d) TC1411VOA713: Tape and Reel, 1A Single MOSFET driver, 8LD SOIC package, -40°C to +125°C.
PA = Plastic DIP (300 mil Body), 8-lead * MSOP package is only available in E-Temp.	a) TC1411NCPA: 1A Single MOSFET driver, 8LD PDIP package, 0°C to +70°C.
	b) TC1411NEPA: 1A Single MOSFET driver, 8LD PDIP package, -40°C to +85°C.
	c) TC1411NEUA: 1A Single MOSFET driver, 8LD MSOP package, -40°C to +85°C.
	d) TC1411NVPA: 1A Single MOSFET driver, 8LD PDIP package, -40°C to +125°C.

NOTES:

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Customers should contact their distributor, representative or Field Application Engineer (FAE) for support. Local sales offices are also available to help customers. A listing of sales offices and locations is included in the back of this document.

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